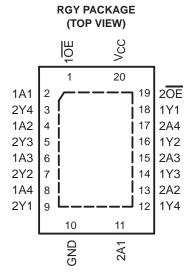
SCES430A - MARCH 2003 - REVISED MARCH 2003

- Optimized for 1.8-V Operation and is 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Sub 1-V Operable
- Max t<sub>pd</sub> of 1.7 ns at 1.8 V
- Low Power Consumption, 20-μA Max I<sub>CC</sub>
- ±8-mA Output Drive at 1.8 V
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)



#### description/ordering information

This octal buffer/driver is operational at 0.8-V to 2.7-V  $V_{CC}$ , but is designed specifically for 1.65-V to 1.95-V  $V_{CC}$  operation.

The SN74AUC240 is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

This device is organized as two 4-bit buffers/drivers with separate output-enable ( $\overline{OE}$ ) inputs. When  $\overline{OE}$  is low, the device passes data from the A inputs to the Y outputs. When  $\overline{OE}$  is high, the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### ORDERING INFORMATION

TA	PACKAG	3E†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 85°C	QFN – RGY	Tape and reel	SN74AUC240RGYR	MS240

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



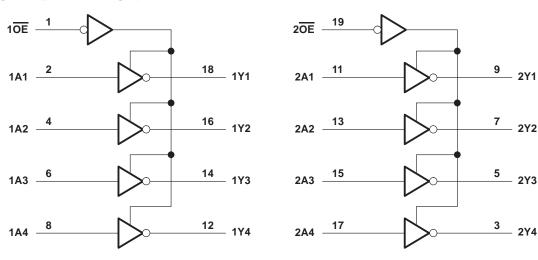
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# FUNCTION TABLE (each 4-bit buffer/driver)

INP	JTS	OUTPUT
OE	Α	Υ
L	Н	L
L	L	Н
Н	Χ	Z

#### logic diagram (positive logic)



#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>	
Voltage range applied to any output in the high-impedance or power-off state, V <sub>O</sub>	
(see Note 1)	0.5 V to 3.6 V
Output voltage range, VO (see Note 1)	–0.5 V to $V_{CC}$ + 0.5 V
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)	–50 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	–50 mA
Continuous output current, I <sub>O</sub>	±20 mA
Continuous current through V <sub>CC</sub> or GND	±100 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 2)	37°C/W
Storage temperature range, T <sub>stg</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.



<sup>2.</sup> The package thermal impedance is calculated in accordance with JESD 51-5.

#### recommended operating conditions (see Note 3)

			MIN	MAX	UNIT
Vcc	Supply voltage		0.8	2.7	V
		V <sub>CC</sub> = 0.8 V	VCC		
$V_{IH}$	High-level input voltage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$	0.65 × V <sub>CC</sub>		V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		
		V <sub>CC</sub> = 0.8 V		0	
$V_{IL}$	Low-level input voltage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$		0.35 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V		0.7	
٧ <sub>I</sub>	Input voltage		0	3.6	V
.,	0 !:	Active state	0	Vcc	.,
VO	V <sub>O</sub> Output voltage	3-state	0	3.6	V
		V <sub>CC</sub> = 0.8 V		-0.7	
		V <sub>CC</sub> = 1.1 V		-3	
loh	High-level output current	V <sub>CC</sub> = 1.4 V		-5	mA
		V <sub>CC</sub> = 1.65 V		-8	
		V <sub>CC</sub> = 2.3 V		-9	
		V <sub>CC</sub> = 0.8 V		0.7	
		V <sub>CC</sub> = 1.1 V		3	
loL	Low-level output current	V <sub>CC</sub> = 1.4 V		5	mA
		V <sub>CC</sub> = 1.65 V		8	
		V <sub>CC</sub> = 2.3 V		9	
Δt/Δν	Input transition rise or fall rate	•		20	ns/V
TA	Operating free-air temperature		-40	85	°C

NOTE 3: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

P	ARAMETER	TEST CONDI	TIONS	vcc	MIN	TYP <sup>†</sup>	MAX	UNIT
		I <sub>OH</sub> = -100 μA		0.8 V to 2.7 V	V <sub>CC</sub> -0.	.1		
		$I_{OH} = -0.7 \text{ mA}$		0.8 V		0.55		
l ,,		$I_{OH} = -3 \text{ mA}$		1.1 V	0.8			V
VOH		$I_{OH} = -5 \text{ mA}$		1.4 V	1			V
		$I_{OH} = -8 \text{ mA}$		1.65 V	1.2			
		$I_{OH} = -9 \text{ mA}$		2.3 V	1.8			
		I <sub>OL</sub> = 100 μA		0.8 V to 2.7 V			0.2	
		$I_{OL} = 0.7 \text{ mA}$		0.8 V		0.25		
\ \/ - ·		$I_{OL} = 3 \text{ mA}$		1.1 V			0.3	V
VOL		$I_{OL} = 5 \text{ mA}$		1.4 V			0.4	V
		$I_{OL} = 8 \text{ mA}$		1.65 V			0.45	
		$I_{OL} = 9 \text{ mA}$		2.3 V			0.6	
IĮ	A and OE inputs	$V_I = V_{CC}$ or GND		0 to 2.7 V			±5	μΑ
l <sub>off</sub>		$V_I$ or $V_O = 2.7 V$		0			±10	μΑ
loz		$V_O = V_{CC}$ or GND		2.7 V			±10	μΑ
Icc		$V_I = V_{CC}$ or GND,	I <sub>O</sub> = 0	0.8 V to 2.7 V			20	μΑ
Ci	_	$V_I = V_{CC}$ or GND	_	2.5 V		2.5	3	pF
Co		$V_O = V_{CC}$ or GND		2.5 V		5.5	6	pF

<sup>&</sup>lt;sup>†</sup> All typical values are at  $T_A = 25$ °C.

# switching characteristics over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = ± 0.		V <sub>CC</sub> =	: 1.5 V .1 V		c = 1.8 0.15 V		V <sub>CC</sub> = ± 0.		UNIT
	(INPUT)	(001701)	TYP	MIN	MAX	MIN	MAX	MIN	TYP	MAX	MIN	MAX	
t <sub>pd</sub>	А	Υ	4.8	1.2	3.3	0.8	2	0.7	1.1	1.7	0.6	1.3	ns
t <sub>en</sub>	ŌĒ	Υ	6.4	1.4	4	0.9	2.6	0.8	1.2	2.1	0.7	1.5	ns
t <sub>dis</sub>	ŌĒ	Υ	8.7	2	5.8	1.8	3.9	1.8	2.5	4	0.3	3	ns

# switching characteristics over recommended operating free-air temperature range, $C_L$ = 30 pF (unless otherwise noted) (see Figure 1)

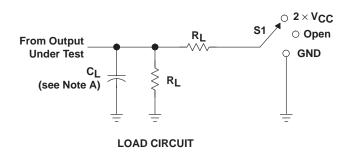
PARAMETER	FROM	TO		C = 1.8	V	V <sub>CC</sub> =	2.5 V 2 V	UNIT
	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	
<sup>t</sup> pd	А	Y	1	1.4	2.1	0.9	1.6	ns
t <sub>en</sub>	ŌĒ	Y	1.1	1.7	2.7	1	2	ns
<sup>t</sup> dis	ŌĒ	Υ	1.9	2.5	4	1	2	ns



## operating characteristics, $T_A = 25^{\circ}C$

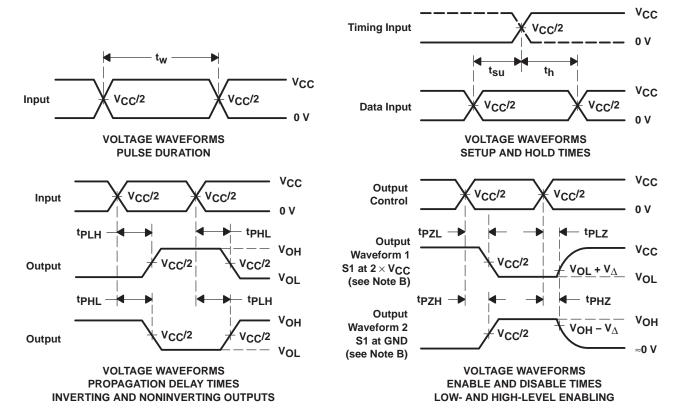
	PARAMETE	R	TEST	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = 1.2 V	V <sub>CC</sub> = 1.5 V	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V	UNIT
	TAKAMETE		CONDITIONS	TYP	TYP	TYP	TYP	TYP	ONIT
	Power	Outputs enabled	( 40 MH-	21	21	21	22	25	י
C <sub>pd</sub>	dissipation capacitance	Outputs disabled	f = 10 MHz	3	3	3	3	5	pF

#### PARAMETER MEASUREMENT INFORMATION



TEST	S1
tPLH/tPHL	Open
tPLZ/tPZL	2×V <sub>CC</sub>
tPHZ/tPZH	GND

VCC	CL	RL	$v_{\scriptscriptstyle\Delta}$
0.8 V	15 pF	<b>2 k</b> Ω	0.1 V
1.2 V $\pm$ 0.1 V	15 pF	<b>2 k</b> Ω	0.1 V
1.5 V ± 0.1 V	15 pF	<b>2 k</b> Ω	0.1 V
1.8 V $\pm$ 0.15 V	15 pF	<b>2 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	15 pF	<b>2 k</b> Ω	0.15 V
1.8 V ± 0.15 V	30 pF	<b>1 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	30 pF	500 Ω	0.15 V
1	I	I	1



- NOTES: A.  $C_L$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_0 = 50 \Omega$ , slew rate  $\geq$  1 V/ns.
  - D. The outputs are measured one at a time with one transition per measurement.
  - E. tpLz and tpHz are the same as tdis.
  - F. tpzL and tpzH are the same as ten.
  - G. tpLH and tpHL are the same as tpd.
  - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





#### PACKAGE OPTION ADDENDUM

10-Dec-2020

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN74AUC240RGYR	ACTIVE	VQFN	RGY	20	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	MS240	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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### **PACKAGE MATERIALS INFORMATION**

www.ti.com 3-Jun-2022

#### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUC240RGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1

## **PACKAGE MATERIALS INFORMATION**

www.ti.com 3-Jun-2022



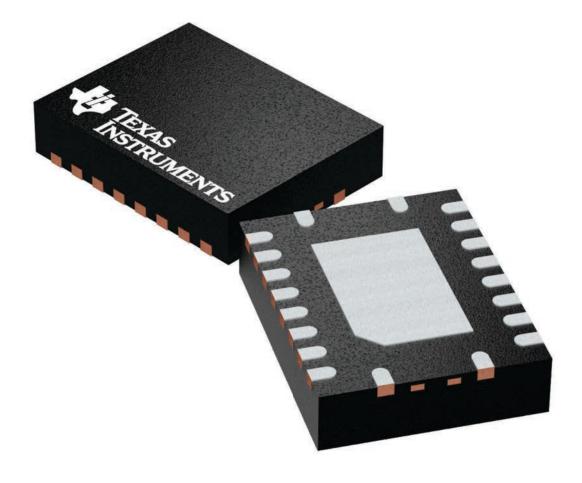
#### \*All dimensions are nominal

	Device	Package Type	Package Drawing	ing Pins SI		Length (mm)	Width (mm)	Height (mm)	
I	SN74AUC240RGYR	VQFN	RGY	20	3000	356.0	356.0	35.0	

3.5 x 4.5, 0.5 mm pitch

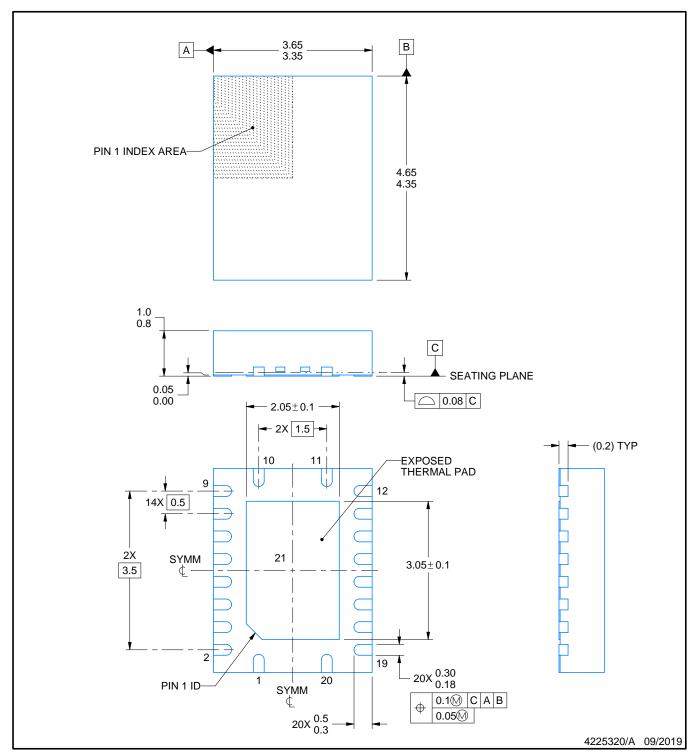
PLASTIC QUAD FGLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





PLASTIC QUAD FLATPACK - NO LEAD

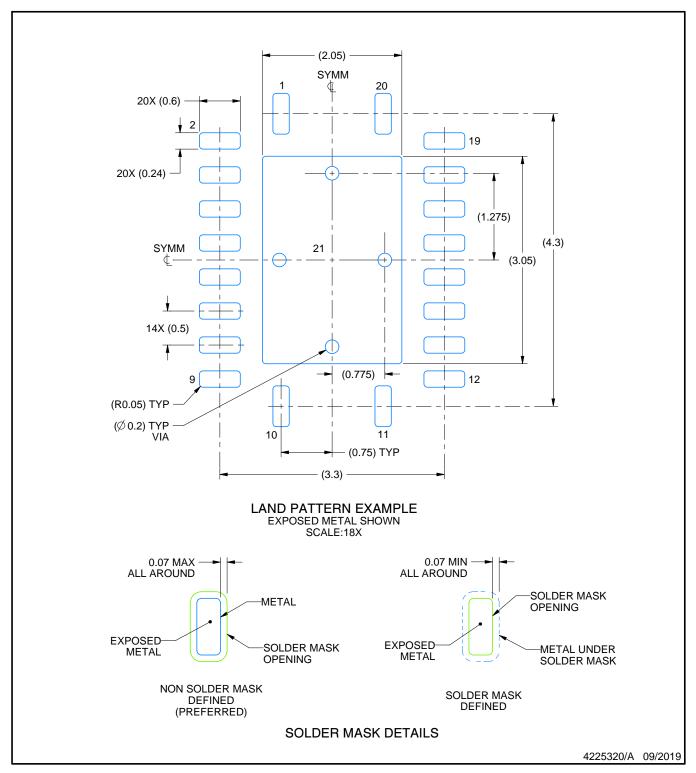


#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD

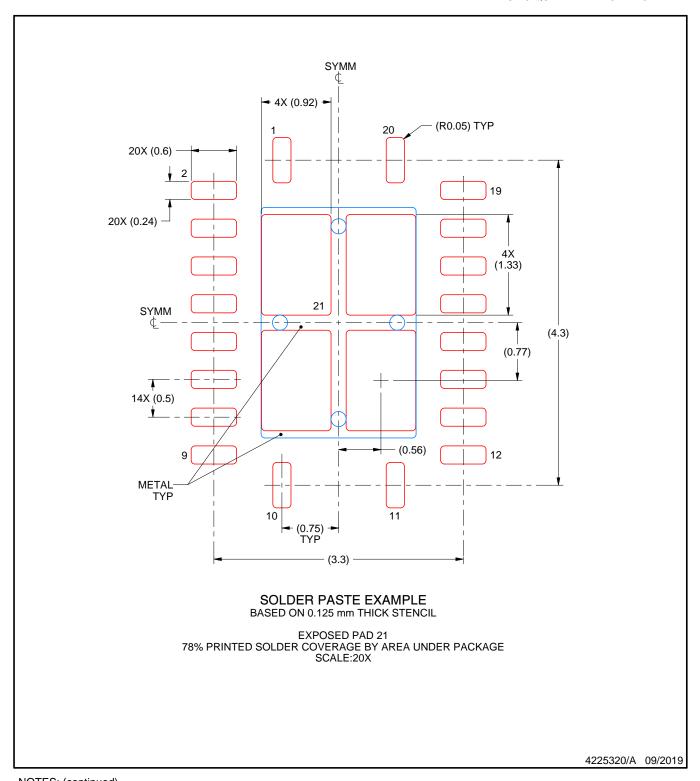


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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